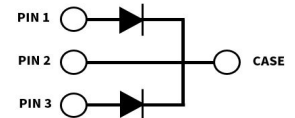


C4D10120D

4th Generation 1200 V, 10 A Silicon Carbide Schottky Diode

Description

With the performance advantages of a Silicon Carbide (SiC) Schottky Barrier diode, power electronics systems can expect to meet higher efficiency standards than Si-based solutions, while also reaching higher frequencies and power densities. SiC diodes can be easily paralleled to meet various application demands, without concern of thermal runaway. In combination with the reduced cooling requirements and improved thermal performance of SiC products, SiC diodes are able to provide lower overall system costs in a variety of diverse applications.



Package Types: TO-247-3
Marking: C4D10120

Features

- High-Frequency Operation
- Zero Reverse Recovery Current / Forward Recovery Voltage
- Temperature-Independent Switching Behavior
- Parallel Devices Without Thermal Runaway

Typical Applications

- Boost Diodes in PFC or DC/DC Stages
- Free Wheeling Diodes in Inverter Stages
- Switch Mode Power Supplies
- Solar Inverters
- AC/DC Converters

Maximum Ratings ($T_c = 25^\circ\text{C}$ Unless Otherwise Specified)

* Per Leg, ** Per Device

Parameter	Symbol	Value	Unit	Test Conditions	Notes
Repetitive Peak Reverse Voltage	V_{RRM}	1200	V		
Surge Peak Reverse Voltage	V_{RSM}	1300			
DC Blocking Voltage	V_{DC}	1200			
Continuous Forward Current (Per Leg/Per Device)	I_F	19/38	A	$T_c = 25^\circ\text{C}$	Fig. 3
		9/18		$T_c = 135^\circ\text{C}$	
		5/10		$T_c = 160^\circ\text{C}$	
Repetitive Peak Forward Surge Current	I_{FRM}	26*		$T_c = 25^\circ\text{C}, t_p = 10 \text{ ms}, \text{Half Sine Wave}$	
		18*		$T_c = 110^\circ\text{C}, t_p = 10 \text{ ms}, \text{Half Sine Wave}$	
Non-Repetitive Forward Surge Current	I_{FSM}	46*		$T_c = 25^\circ\text{C}, t_p = 10 \text{ ms}, \text{Half Sine Wave}$	Fig. 8
		36*		$T_c = 110^\circ\text{C}, t_p = 10 \text{ ms}, \text{Half Sine Wave}$	
Non-Repetitive Peak Forward Surge Current	$I_{F,Max}$	400*		$T_c = 25^\circ\text{C}, t_p = 10 \mu\text{s}, \text{Pulse}$	
		320*		$T_c = 110^\circ\text{C}, t_p = 10 \mu\text{s}, \text{Pulse}$	
Power Dissipation (Per Leg/Per Device)	P_{tot}	93/187	W	$T_c = 25^\circ\text{C}$	Fig. 4
		40/81		$T_c = 110^\circ\text{C}$	
i^2t value	$\int i^2 dt$	10.6*	A^2s	$T_c = 25^\circ\text{C}, t_p = 10 \text{ ms}$	
		6.5*		$T_c = 110^\circ\text{C}, t_p = 10 \text{ ms}$	
Diode dV/dt Ruggedness	dV/dt	200	V/ns	$V_R = 0-650\text{V}$	



Electrical Characteristics

Parameter	Symbol	Typ.	Max.	Unit	Test Conditions	Notes
Forward Voltage	V_F	1.4	1.8	V	$I_F = 5\text{ A}, T_J = 25\text{ }^{\circ}\text{C}$	Fig. 1
		1.9	3		$I_F = 5\text{ A}, T_J = 175\text{ }^{\circ}\text{C}$	
Reverse Current	I_R	20	150	μA	$V_R = 1200\text{ V}, T_J = 25\text{ }^{\circ}\text{C}$	Fig. 2
		40	300		$V_R = 1200\text{ V}, T_J = 175\text{ }^{\circ}\text{C}$	
Total Capacitive Charge	Q_C	27		nC	$V_R = 800\text{ V}, T_J = 25\text{ }^{\circ}\text{C}$ $I_F = 5\text{ A}, di/dt = 200\text{ A}/\mu\text{s}$	Fig. 5
Total Capacitance	C	390		pF	$V_R = 0\text{ V}, T_J = 25\text{ }^{\circ}\text{C}, f = 1\text{ MHz}$	Fig. 6
		27			$V_R = 400\text{ V}, T_J = 25\text{ }^{\circ}\text{C}, f = 1\text{ MHz}$	
		20			$V_R = 800\text{ V}, T_J = 25\text{ }^{\circ}\text{C}, f = 1\text{ MHz}$	
Capacitance Stored Energy	E_C	8.0		μJ	$V_R = 800\text{ V}$	Fig. 7

Notes:
SiC Schottky Diodes are majority carrier devices, so there is no reverse recovery charge.

Thermal & Mechanical Characteristics

Parameter	Symbol	Value	Unit	Notes
Thermal Resistance, Junction to Case (Typical)	$R_{\theta, JC (TYP)}$	0.8** 1.6*	$^{\circ}\text{C} / \text{W}$	
Junction Temperature	T_J	-55 to +175	$^{\circ}\text{C}$	
Case & Storage Temperature	T_C	-55 to +135		
TO-247 Mounting Torque	-	1	Nm	M3 Screw
		8.8	lbf-in	6-32 Screw

* Per Leg, ** Per Device

Typical Performance

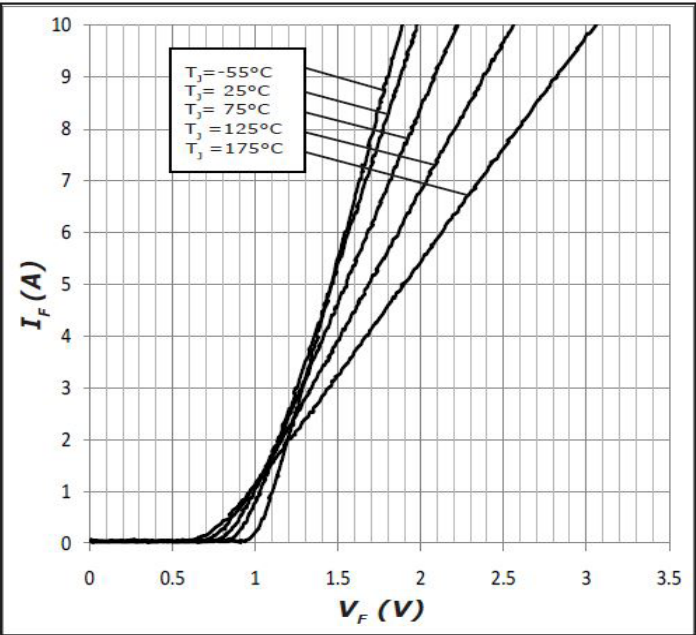


Figure 1
Forward Characteristics

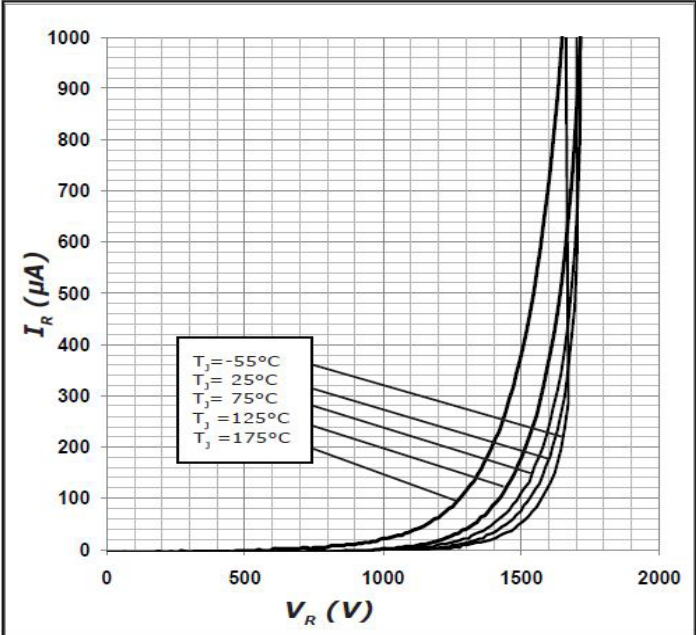


Figure 2
Reverse Characteristics

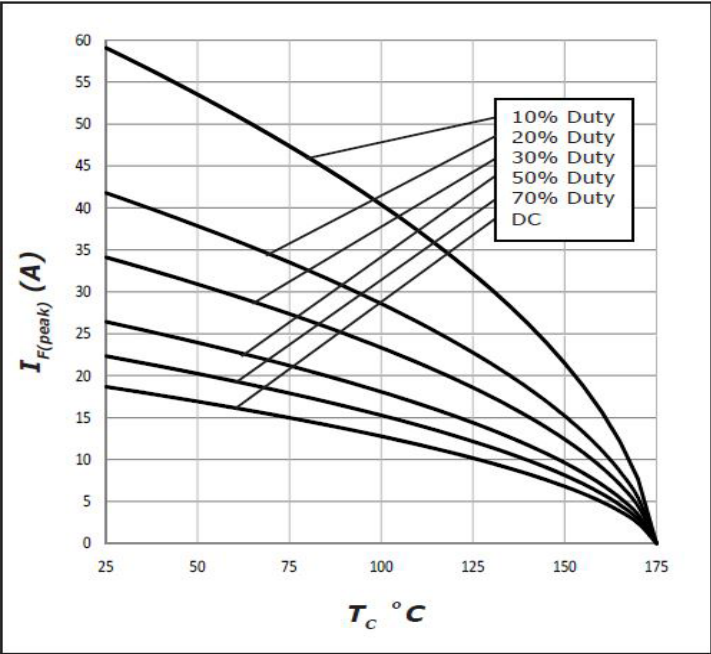


Figure 3
Current Derating

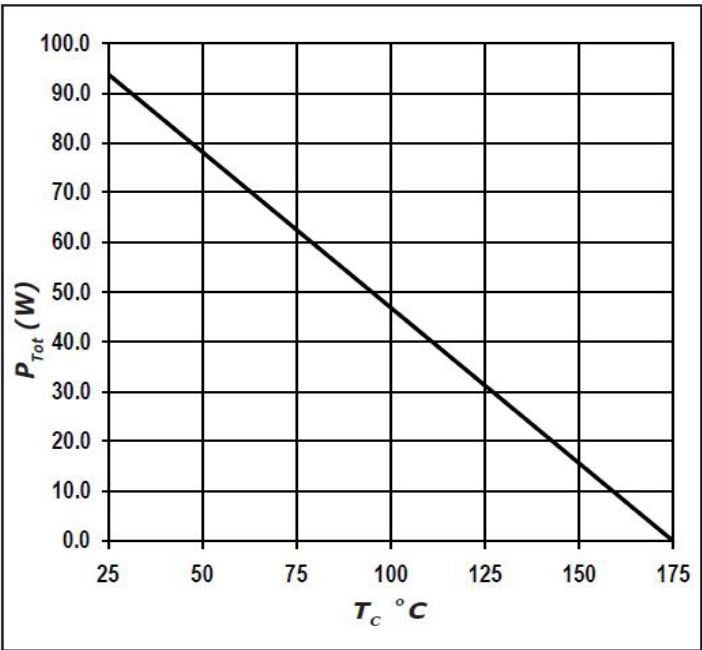


Figure 4
Power Derating

Typical Performance

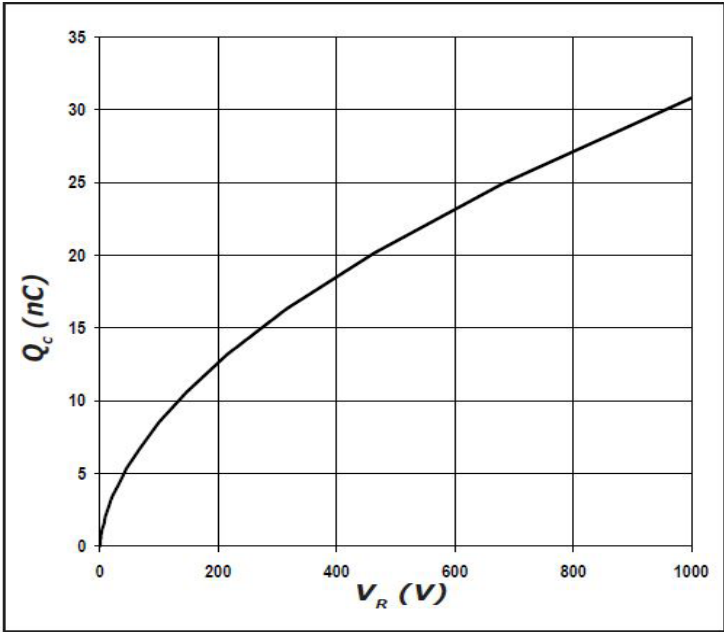


Figure 5
Total Capacitance Charge vs. Reverse Voltage

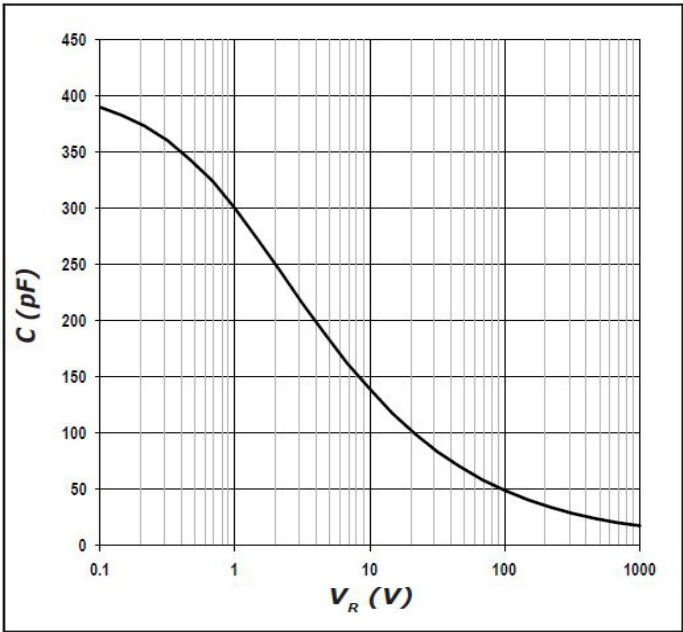


Figure 6
Capacitance vs. Reverse Voltage

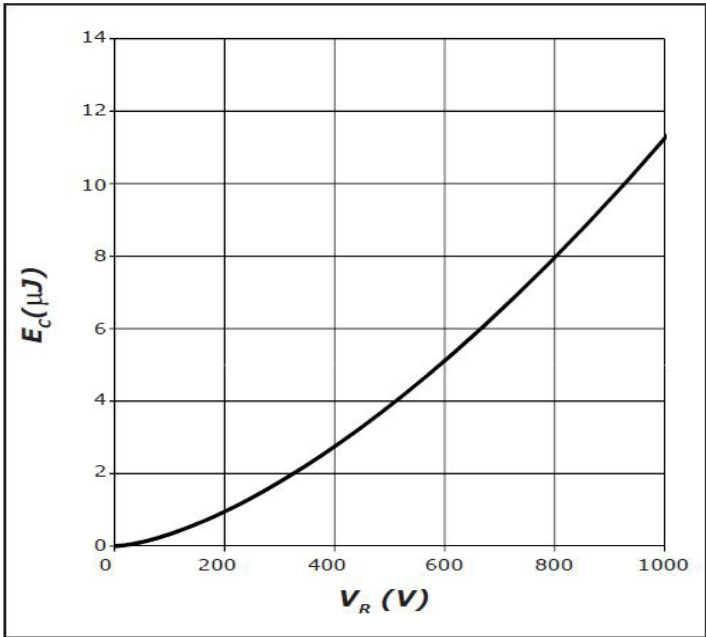


Figure 7
Capacitance Stored Energy

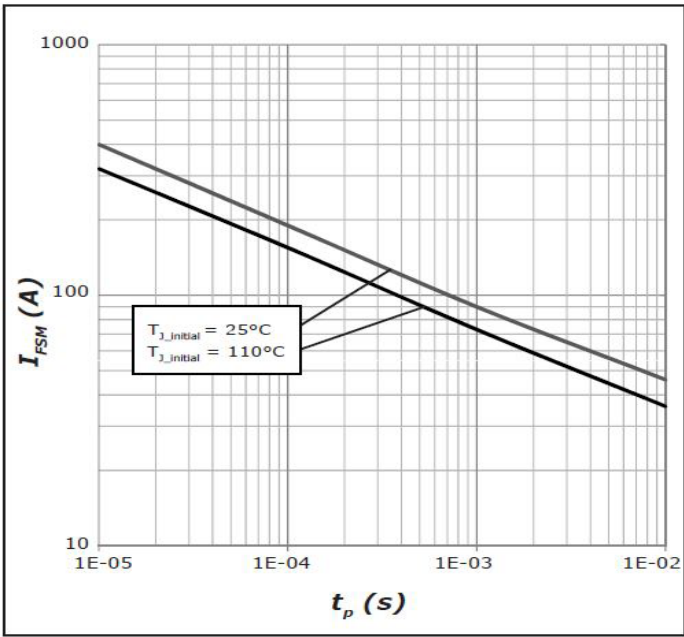


Figure 8
Non-Repetitive Peak Forward Surge Current vs. Pulse Duration

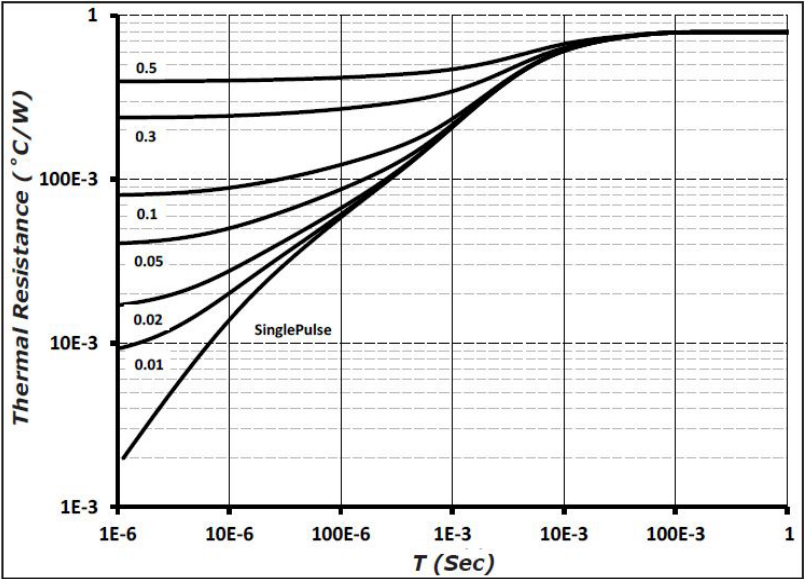
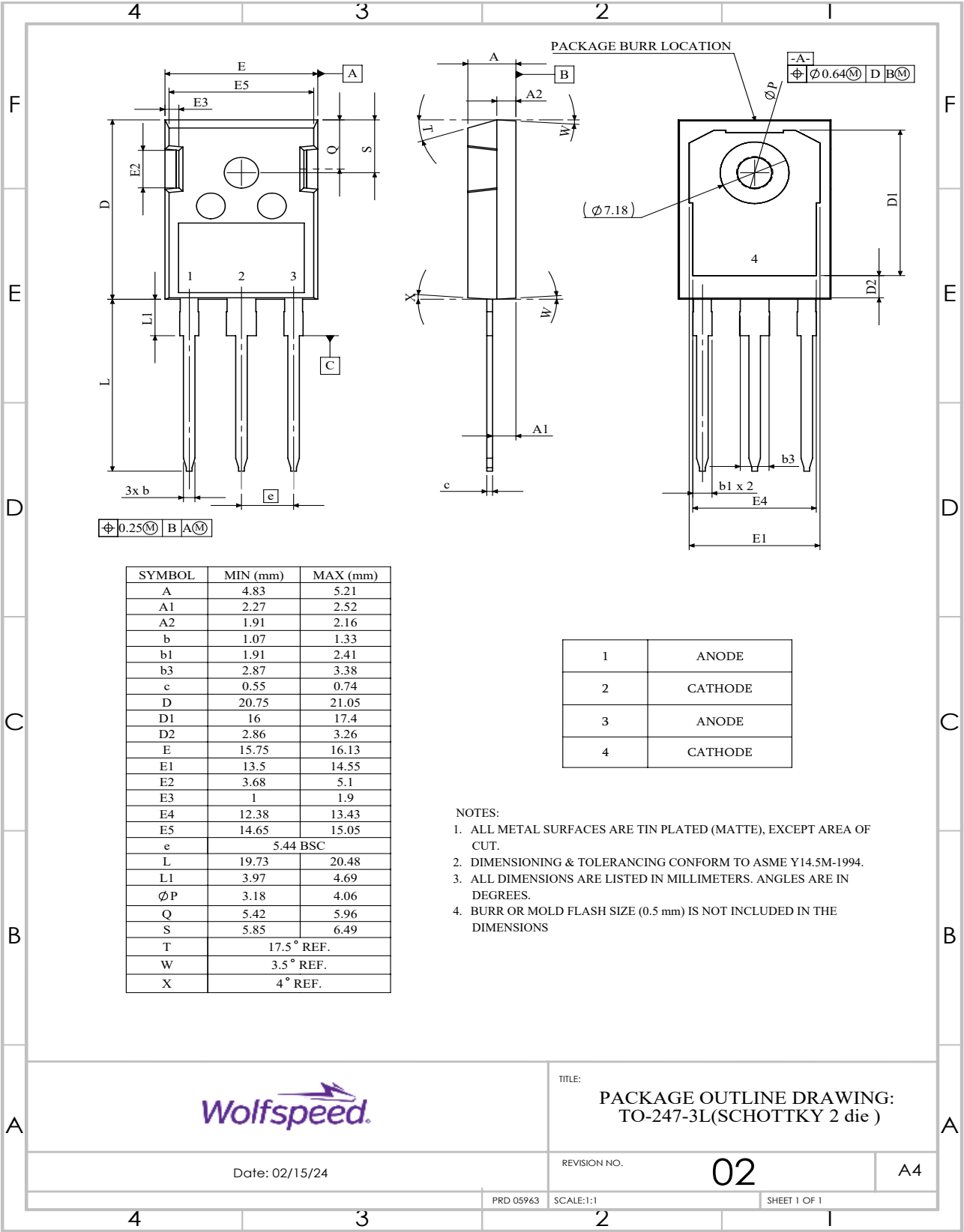


Figure 9
Transient Thermal Impedance

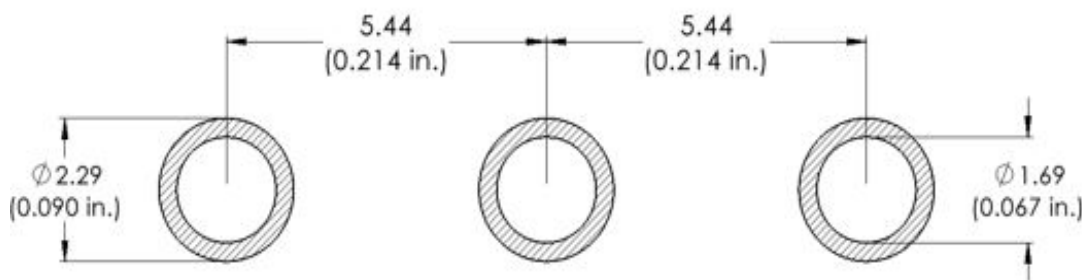
Package Dimensions & Pin-Out

Package: TO-247-3



Recommended Solder Pad Layout

Primary dimensions shown in mm.



Diode Model

V_T R_T

$$Vf_T = V_T + If * R_T$$
$$V_T = 0.96 + (T_j * -1.22 * 10^{-3})$$
$$R_T = 0.08 + (T_j * 8.5 * 10^{-4})$$

Note: T_j = Diode Junction Temperature In Degrees Celsius, valid from 25°C to 175°C

Product Ordering Information

Order Number	Packing Type
C4D10120D	Tube

REACH, RoHS, and Halogen-Free compliance documentation available for this product.



Revision History

Document Version	Date of Release	Description of Changes
H	September- 2016	Initial Release
9	May-2023	Update Branding, Forward Voltage Test Conditions, POD, Package Image, solder pad layout
10	November-2023	Corrected V_F test conditions, added dV/dT ruggedness characteristic, updated Q_C , I_F , P_{tot} test conditions
11	September - 2024	Legal Disclaimer and POD Updated

Notes & Disclaimer

WOLFSPEED PROVIDES TECHNICAL AND RELIABILITY DATA, DESIGN RESOURCES, APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, AND OTHER RESOURCES “AS IS” AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, WITH RESPECT THERETO, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, SUITABILITY, FITNESS FOR A PARTICULAR PURPOSE, OR NON-INFRINGEMENT OF THIRD-PARTY INTELLECTUAL PROPERTY RIGHTS.

This document and the information contained herein are subject to change without notice. Any such change shall be evidenced by the publication of an updated version of this document by Wolfspeed. No communication from any employee or agent of Wolfspeed or any third party shall effect an amendment or modification of this document. No responsibility is assumed by Wolfspeed for any infringement of patents or other rights of third parties which may result from use of the information contained herein. No license is granted by implication or otherwise under any patent or patent rights of Wolfspeed.

The information contained in this document (excluding examples, as well as figures or values that are labeled as “typical”) constitutes Wolfspeed’s sole published specifications for the subject product. “Typical” parameters are the average values expected by Wolfspeed in large quantities and are provided for informational purposes only. Any examples provided herein have not been produced under conditions intended to replicate any specific end use. Product performance can and does vary due to a number of factors.

This product has not been designed or tested for use in, and is not intended for use in, any application in which failure of the product would reasonably be expected to cause death, personal injury, or property damage. For purposes of (but without limiting) the foregoing, this product is not designed, intended, or authorized for use as a critical component in equipment implanted into the human body, life-support machines, cardiac defibrillators, and similar emergency medical equipment; air traffic control systems; or equipment used in the planning, construction, maintenance, or operation of nuclear facilities. Notwithstanding any application-specific information, guidance, assistance, or support that Wolfspeed may provide, the buyer of this product is solely responsible for determining the suitability of this product for the buyer’s purposes, including without limitation (1) selecting the appropriate Wolfspeed products for the buyer’s application, (2) designing, validating, and testing the buyer’s application, and (3) ensuring the buyer’s application meets applicable standards and any other legal, regulatory, and safety-related requirements.

RoHS Compliance

The levels of RoHS restricted materials in this product are below the maximum concentration values (also referred to as the threshold limits) permitted for such substances, or are used in an exempted application, in accordance with EU Directive 2011/65/EC (RoHS2), as implemented January 2, 2013. RoHS Declarations for this product can be obtained from your Wolfspeed representative or from the Product Documentation sections of www.wolfspeed.com.

REACH Compliance

REACH substances of high concern (SVHCs) information is available for this product. Since the European Chemical Agency (ECHA) has published notice of their intent to frequently revise the SVHC listing for the foreseeable future, please contact your Wolfspeed representative to ensure you get the most up-to-date REACH SVHC Declaration. REACH banned substance information (REACH Article 67) is also available upon request.

Contact info:

4600 Silicon Drive
Durham, NC 27703 USA
Tel: +1.919.313.5300
www.wolfspeed.com/power

© 2024 Wolfspeed, Inc. All rights reserved. Wolfspeed® and the Wolfstreak logo are registered trademarks and the Wolfspeed logo is a trademark of Wolfspeed, Inc.
PATENT: <https://www.wolfspeed.com/legal/patents>

The information in this document is subject to change without notice.